



BCP 54/ 55/ 56

NPN MEDIUM POWER TRANSISTORS IN SOT223

Features

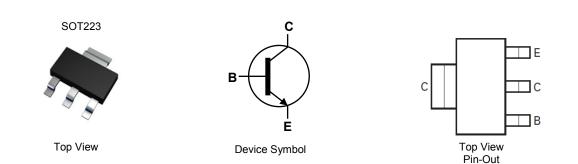
- BV_{CEO} > 45V, 60V & 80V
- I_C = 1A High Continuous Collector Current
- I_{CM} = 2A Peak Pulse Current
- 2W Power Dissipation
- Low Saturation Voltage V_{CE(sat)} < 500mV @ 0.5A
- Gain Groups 10 and 16
- Complementary PNP Types: BCP51, 52 and 53
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen- and Antimony-Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/quality/product-definitions/</u>

Mechanical Data

- Case: SOT223
- Case Material: Molded Plastic. "Green" Molding Compound; UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.112 grams (Approximate)

Applications

- Medium Power Switching or Amplification Applications
- AF Driver and Output Stages



Ordering Information (Note 4)

Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
BCP54TA	Standard	BCP 54	7	12	1,000
BCP5410TA	Standard	BCP 5410	7	12	1,000
BCP5416TA	Standard	BCP 5416	7	12	1,000
BCP55TA	Standard	BCP 55	7	12	1,000
BCP5510TA	Standard	BCP 5510	7	12	1,000
BCP5516TA	Standard	BCP 5516	7	12	1,000
BCP56TA	Standard	BCP 56	7	12	1,000
BCP5610TA	Standard	BCP 5610	7	12	1,000
BCP5616TA	Standard	BCP 5616	7	12	1,000
BCP5616TC	Standard	BCP 5616	13	12	4,000

Notes:

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

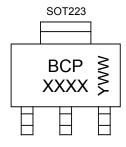
2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



Marking Information



BCP = Product Type Marking Code, Line 1 XXXX = Product Type Marking Code, Line 2 as follows:

> BCP55 = 55 BCP5510 = 5510 BCP5516 = 5516

BCP56 = 56 BCP5610 = 5610 BCP5616 = 5616

Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	BCP54	BCP55	BCP56	Unit
Collector-Base Voltage	V _{CBO}	45	60	100	V
Collector-Emitter Voltage	V _{CEO}	45	60	80	V
Emitter-Base Voltage	V _{EBO}	5			V
Continuous Collector Current	lc	1		A	
Peak Pulse Collector Current (Single pulse)	Iсм	2			
Continuous Base Current	IB	100			m (
Peak Pulse Base Current (Single pulse)	I _{BM}		200		mA

BCP54 = 54

BCP5410 = 5410

BCP5416 = 5416

YWW = Date Code Marking

Y or \overline{Y} = Last Digit of Year (ex: 5= 2015) WW or $\overline{W}W$ = Week Code (01~53)

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Power Dissipation (Note 5)		PD	2	W
Thermal Resistance, Junction to Ambient (Note 5)		R _{0JA}	62	°C/W
Thermal Resistance, Junction to Leads (Note 6)		R _{θJL}	19.4	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C	

ESD Ratings (Note 7)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

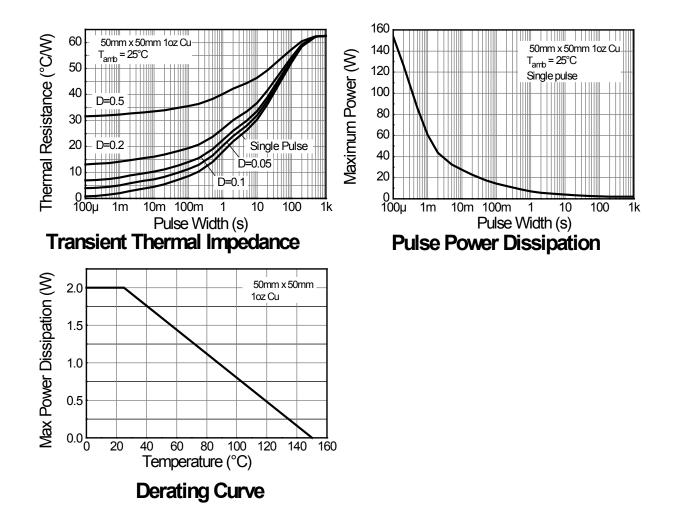
Notes: 5. For a device mounted with the collector lead on 50mm x 50mm 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in steady-state.

6. Thermal resistance from junction to solder-point (at the end of the collector lead).

7. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Thermal Characteristics and Derating Information





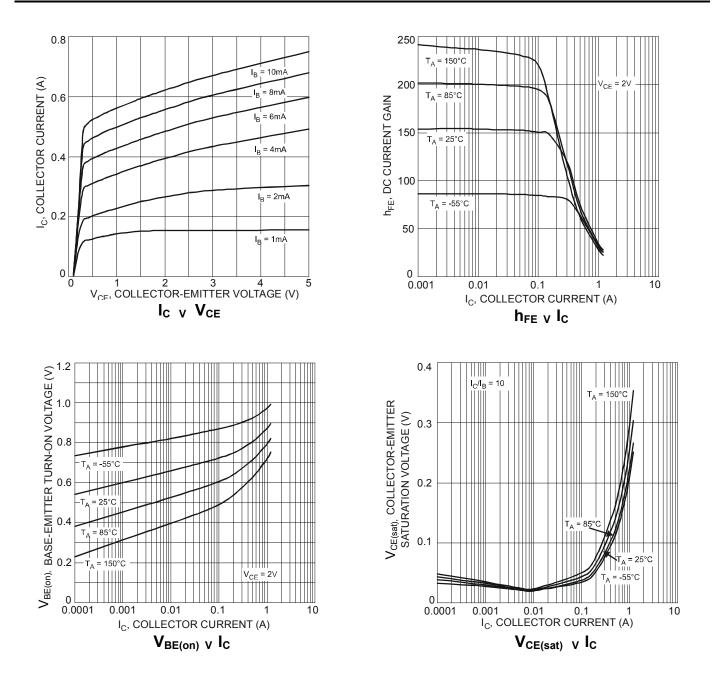
Electrical Characteristics (@ T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
	BCP54		45				
Collector-Base Breakdown Voltage	BCP55	ВV _{CBO}	60	-	-	V	I _C = 100μΑ
bleakdown voltage	BCP56		100				
O-lla stan Envittan	BCP54	BV _{CEO}	45			V	I _C = 10mA
Collector-Emitter Breakdown Voltage (Note 8)	BCP55		60	-	-		
Dieakdowii Voltage (Note 0)	BCP56		80				
Emitter-Base Breakdown Voltage		BV _{EBO}	5	-	-	V	I _E = 10μΑ
Collector Cut-Off Current		I _{CBO}	-	-	0.1 20	μA	V _{CB} = 30V
							V _{CB} = 30V, T _A = +150°C
Emitter Cut-Off Current		I _{EBO}	-	-	20	nA	V _{EB} = 4V
	All versions	h _{FE}	25	-	-		$I_{C} = 5mA, V_{CE} = 2V$
			40	-	250		I_{C} = 150mA, V_{CE} = 2V
DC Current Gain (Note 8)			25	-	-		$I_{\rm C}$ = 500mA, $V_{\rm CE}$ = 2V
	10 gain grp	. =	63	-	160		I_{C} = 150mA, V_{CE} = 2V
	16 gain grp		100	-	250		I_{C} = 150mA, V_{CE} = 2V
Collector-Emitter Saturation Voltage (Note 8)		V _{CE(sat)}	-	-	0.5	V	I _C = 500mA, I _B = 50mA
Base-Emitter Turn-On Voltage (Note 8)		V _{BE(on)}	-	-	1.0	V	I _C = 500mA, V _{CE} = 2V
Transition frequency		f⊤	150	-	-	MHz	I _C = 50mA, V _{CE} = 10V f = 100MHz
Output Capacitance		Cobo	-	-	25	pF	V _{CB} = 10V, f = 1MHz

Note: 8. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.

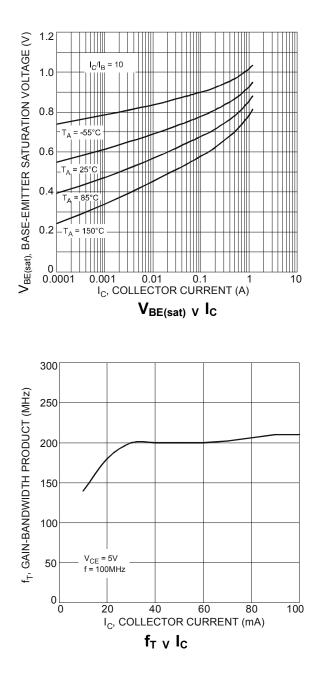


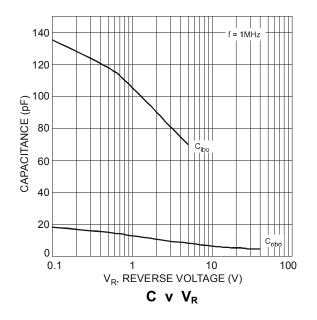
Typical Electrical Characteristics (@ T_A = +25°C, unless otherwise specified.)





Typical Electrical Characteristics (@ T_A = +25°C, unless otherwise specified.)

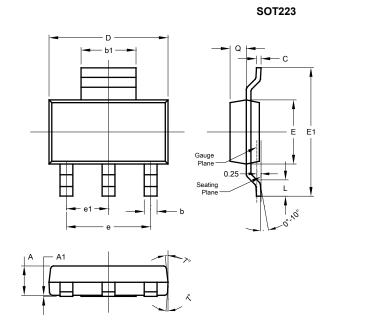






Package Outline Dimensions

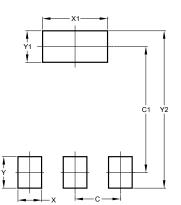
Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT223						
Dim	Min	Max	Тур			
Α	1.55	1.65	1.60			
A1	0.010	0.15	0.05			
b	0.60	0.80	0.70			
b1	2.90	3.10	3.00			
С	0.20	0.30	0.25			
D	6.45	6.55	6.50			
Е	3.45	3.55	3.50			
E1	6.90	7.10	7.00			
е	-	-	4.60			
e1	-	-	2.30			
L	0.85	1.05	0.95			
Q	0.84	0.94	0.89			
All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT223

Dimensions	Value (in mm)
С	2.30
C1	6.40
Х	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00



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